

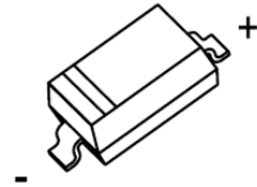


BA T46W SCHOTTKY BARRIER DIODE



FEATURES

- High breakdown voltage
- Low turn-on voltage
- Guard ring construction for transient protection



MARKING: S9

SOD-123

Maximum Ratings @Ta=25°C

Parameter	Symbol	Limit	Unit
Peak repetitive peak reverse voltage	V_{RRM}	100	V
Working peak reverse voltage	V_{RWM}		
Forward continuous current	I_F	150	mA
Repetitive peak forward current (Note 1) @ $t_p < 1.0s$, Duty Cycle < 50%	I_{FRM}	350	mA
Non-repetitive Peak Forward surge current @ $t = 8.3ms$	I_{FSM}	750	mA
Power dissipation	P_D	500	mW
Thermal resistance junction to ambient air	$R_{\theta JA}$	200	°C/W
Junction temperature	T_j	125	°C
Storage temperature	T_{STG}	-55~+150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse breakdown voltage(Note 2)	V_R	$I_R = 100\mu A$	100			V
Reverse voltage leakage current	I_R	$V_{R1} = 1.5V$			0.3	μA
		$V_{R2} = 10V$			0.5	
		$V_{R3} = 50V$			1	
		$V_{R4} = 75V$			2	
Forward voltage(Note 2)	V_F	$I_{F1} = 0.1mA$			0.25	V
		$I_{F2} = 10mA$			0.45	
		$I_{F3} = 250mA$			1	
Diode capacitance	C_T	$V_R = 0, f = 1MHz$		20		pF
		$V_R = 1V, f = 1MHz$		12		

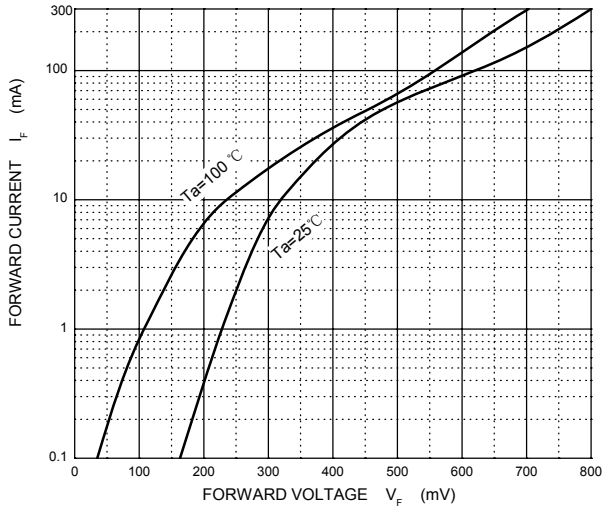
Notes: 1. Part mounted on FR-4 board with recommended pad layout

2. Short duration pulse test used to minimize self-heating effect.

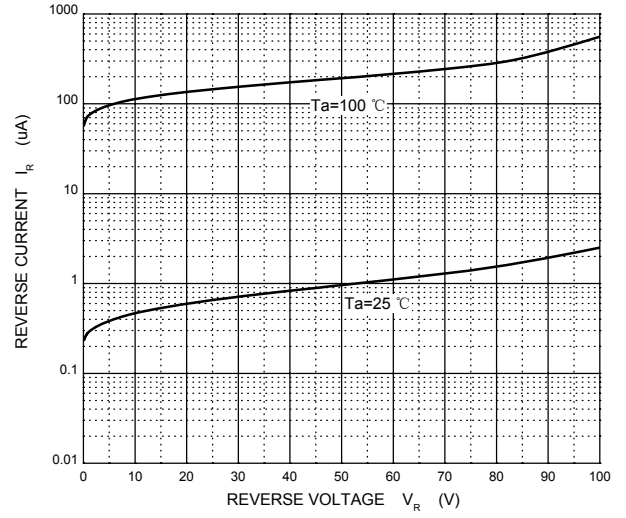


Typical Characteristics

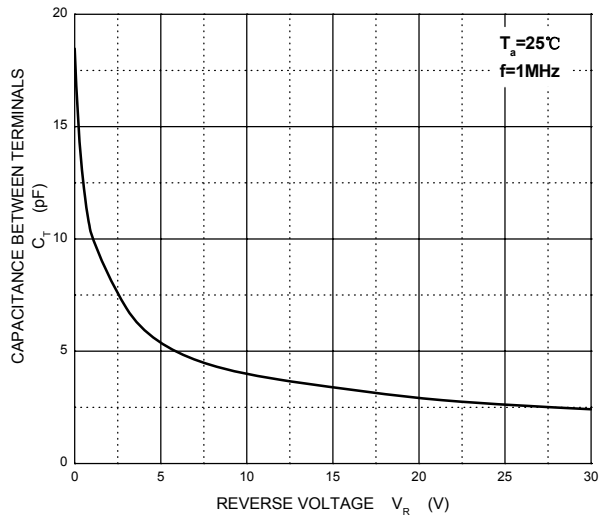
Forward Characteristics



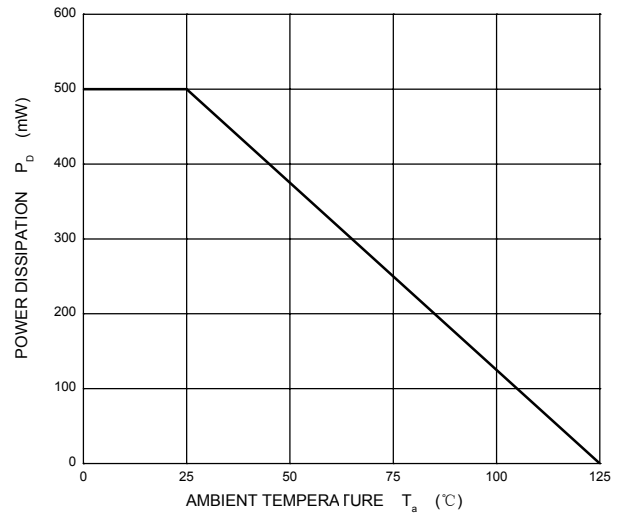
Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

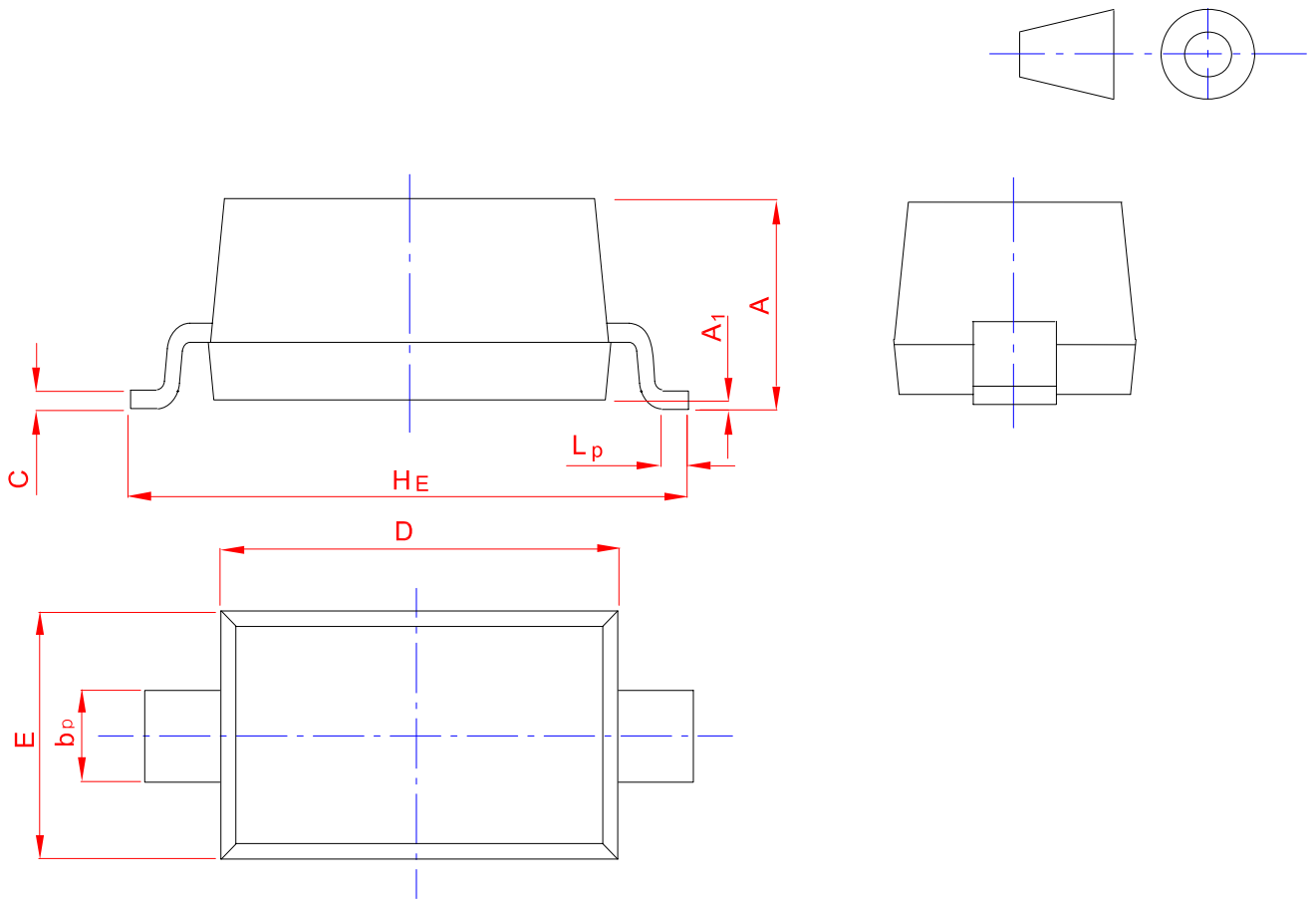




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123



UNIT	A	bp	C	D	E	HE	A1	Lp
mm	1.20	0.60	0.135	2.75	1.65	3.85	0.10	0.50
	0.90	0.50	0.100	2.55	1.55	3.55	0.01	0.20